

**AMENDMENTS TO THE CLAIMS**

**Listing of the claims:**

Following is a listing of all claims in the present application, which listing supersedes all previously presented claims:

1. (Canceled)
2. (Canceled)
3. (Original) A semiconductor integrated circuit device comprising:
  - a power transistor that feeds a large current to a load;
  - a first transistor of which a second electrode and a control electrode are connected respectively to a second electrode and a control electrode of the power transistor;
  - a second transistor of which a second electrode is connected to a first electrode of the first transistor; and
  - a third transistor of which a control electrode is connected to a first electrode of the power transistor and of which a second electrode is connected to a control electrode of the second transistor,
    - wherein the second transistor outputs, at a first electrode thereof, a current signal proportional to a current flowing through the power transistor.
4. (Original) A semiconductor integrated circuit device as claimed in claim 3,
  - wherein a first electrode of the third transistor is connected to the second electrodes of the power transistor and the first transistor, and a direct-current

voltage is applied through a resistor to the second electrode of the third transistor.

5. (Original) A semiconductor integrated circuit device as claimed in claim 3,

wherein the second and third transistors are transistors of opposite polarities, and a potential difference appearing between the second electrode and control electrode of the second transistor is substantially equal to a potential difference appearing between the second electrode and control electrode of the third transistor.

6. (Original) A semiconductor integrated circuit device as claimed in claim 5,

wherein the second transistor is a transistor of a same polarity as the first transistor.

7. (Original) A semiconductor integrated circuit device as claimed in claim 6,

wherein a first electrode of the third transistor is connected to the second electrodes of the power transistor and the first transistor, and a direct-current voltage is applied through a resistor to the second electrode of the third transistor.